



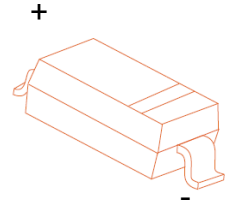
SOD-123 Plastic-Encapsulate Diodes

MMSZ4678-MMSZ4717 ZENER DIODE

Features

- Pb-Free Packages are Available
- Wide Zener Reverse Voltage Range
- Small Package Size for High Density Applications
- ESD Rating of Class 3 (>16 kV) per Human Body Model

SOD-123



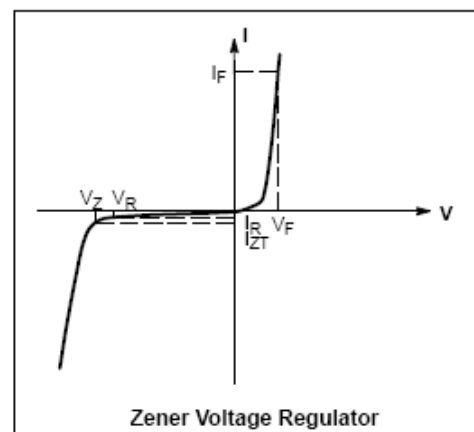
Maximum Ratings ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristic	Symbol	Value	Unit
Forward voltage @ $I_F = 10\text{mA}$	V_F	0.9	V
Power Dissipation	P_D	350	mW
Thermal Resistance, Junction to Ambient Air	$R_{\theta JA}$	357	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_j, T_{STG}	-65 ~ +150	$^\circ\text{C}$

Notes: Device mounted on ceramic PCB; 5.0mm×7.0mm with pad areas 35 mm²

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$ unless otherwise noted)

symbol	Parameter
V_Z	Reverse zener voltage @ I_{ZT}
I_{ZT}	Reverse current
I_R	Reverse leakage current @ V_R
V_R	Reverse voltage
I_F	Forward current
V_F	Forward voltage @ I_F



ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Device	Device Marking	Zener Voltage (Notes 1)				Leakage Current	
		V_Z (Volts)			@ I_{ZT}	I_R @ V_R	
		Min	Nom	Max	μA	μA	Volts
MMSZ4678	CC	1.71	1.8	1.89	50	7.5	1
MMSZ4679	CD	1.90	2.0	2.10	50	5	1
MMSZ4680	CE	2.09	2.2	2.31	50	4	1
MMSZ4681	CF	2.28	2.4	2.52	50	2	1
MMSZ4682	CH	2.565	2.7	2.835	50	1	1
MMSZ4683	CJ	2.85	3.0	3.15	50	0.8	1
MMSZ4684	CK	3.13	3.3	3.47	50	7.5	1.5
MMSZ4685	CM	3.42	3.6	3.78	50	7.5	2
MMSZ4686	CN	3.70	3.9	4.10	50	5	2
MMSZ4687	CP	4.09	4.3	4.52	50	4	2
MMSZ4688	CT	4.47	4.7	4.94	50	10	3
MMSZ4689	CU	4.85	5.1	5.36	50	10	3
MMSZ4690	CV	5.32	5.6	5.88	50	10	4
MMSZ4691	CA	5.89	6.2	6.51	50	10	5
MMSZ4692	CX	6.46	6.8	7.14	50	10	5.1
MMSZ4693	CY	7.13	7.5	7.88	50	10	5.7
MMSZ4694	CZ	7.79	8.2	8.61	50	1	6.2
MMSZ4695	DC	8.27	8.7	9.14	50	1	6.6
MMSZ4696	DD	8.65	9.1	9.56	50	1	6.9
MMSZ4697	DE	9.50	10	10.50	50	1	7.6
MMSZ4698	DF	10.45	11	11.55	50	0.05	8.4
MMSZ4699	DH	11.40	12	12.60	50	0.05	9.1
MMSZ4700	DJ	12.35	13	13.65	50	0.05	9.8
MMSZ4701	DK	13.30	14	14.70	50	0.05	10.6
MMSZ4702	DM	14.25	15	15.75	50	0.05	11.4
MMSZ4703*	DN	15.20	16	16.80	50	0.05	12.1
MMSZ4704	DP	16.15	17	17.85	50	0.05	12.9
MMSZ4705	DT	17.10	18	18.90	50	0.05	13.6
MMSZ4706	DU	18.05	19	19.95	50	0.05	14.4
MMSZ4707	DV	19.00	20	21.00	50	0.01	15.2
MMSZ4708	DA	20.90	22	23.10	50	0.01	16.7
MMSZ4709	DX	22.80	24	25.20	50	0.01	18.2
MMSZ4710	DY	23.75	25	26.25	50	0.01	19.0
MMSZ4711*	EA	25.65	27	28.35	50	0.01	20.4
MMSZ4712	EC	26.60	28	29.40	50	0.01	21.2
MMSZ4713	ED	28.50	30	31.50	50	0.01	22.8
MMSZ4714	EE	31.35	33	34.65	50	0.01	25.0
MMSZ4715	EF	34.20	36	37.80	50	0.01	27.3
MMSZ4716	EH	37.05	39	40.95	50	0.01	29.6
MMSZ4717	EJ	40.85	43	45.15	50	0.01	32.6

1. Nominal Zener voltage is measured with the device junction in thermal equilibrium at $T_L = 30^\circ\text{C} \pm 1^\circ\text{C}$